

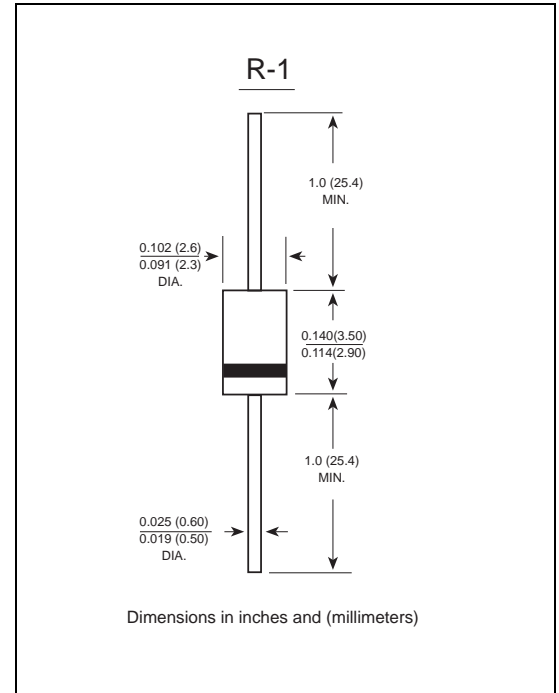
1N17~1N19 1.0Amp Schottky Barrier Rectifiers

Features

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Guardring for overvoltage protection
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: R-1 molded plastic body
 Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
 Polarity: Color band denotes cathode end
 Mounting Position: Any
 Weight: 0.007 ounce, 0.20 grams



Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	1N17	1N18	1N19	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	VOLTS
Maximum RMS voltage	V_{RMS}	14	21	28	VOLTS
Maximum DC blocking voltage	V_{DC}	20	30	40	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_L=90^\circ\text{C}$	$I_{(AV)}$	1.0			Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	25.0			Amps
Maximum instantaneous forward voltage at 1.0A	V_F	0.450	0.550	0.600	Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	0.5 10.0			mA
Typical junction capacitance (NOTE 1)	C_J	110.0			pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0			$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +125			$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted